

N-channel 25 V, 1.9 mOhm, ASFET for hotswap with enhanced SOA in LFPAK56

13 October 2022

Product data sheet

1. General description

N-channel enhancement mode ASFET for hotswap with enhanced SOA in LFPAK56 package optimized for low R_{DSon} and strong safe operating area, optimized for hot-swap, inrush and linear-mode applications.

2. Features and benefits

- Fully optimized Safe Operating Area (SOA) for superior linear mode operation
- Optimized for low R_{DSon} / low I²R conduction losses
- LFPAK56 package for applications that demand the highest performance and reliability in a 30 mm² footprint
- Low leakage <1 µA at 25 °C
- Copper-clip for low parasitic inductance and resistance
- High reliability LFPAK package, qualified to 175 °C

3. Applications

- Hot swap in 12 V 20 V applications
- e-Fuse
- DC switch
- Load switch
- Battery protection

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	25	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	185	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	124	W
Tj	junction temperature			-55	-	175	°C
Static chara	acteristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10		-	1.68	1.88	mΩ
		V _{GS} = 7 V; I _D = 25 A; T _j = 25 °C; <u>Fig. 10</u>		-	2.18	2.4	mΩ
Dynamic ch	naracteristics				-		
Q _{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V;		0.9	5	10	nC
Q _{G(tot)}	total gate charge	T _j = 25 °C; <u>Fig. 12</u> ; <u>Fig. 13</u>		7	16	27	nC

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Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Source-drain diode							
S	softness factor	$ I_{S} = 25 \text{ A}; \text{ d}_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V}; \\ \text{V}_{DS} = 12 \text{ V}; \text{ T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 16} $		-	1.06	-	

[1] 185 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	S	source	mb					
2	S	source		D				
3	S	source	a					
4	G	gate		G_(IETA)				
mb	D	mounting base; connected to drain	1 2 3 4 LFPAK56; Power- SO8 (SOT669)	mbb076 S				

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PSMN1R6-25YLE	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMN1R6-25YLE	1E6L25Y

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Tj = 25 °C unless otherwise stated.

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	25	V
V _{DGR}	drain-gate voltage	$25 \text{ °C} \le \text{T}_{j} \le 175 \text{ °C}; \text{R}_{\text{GS}} = 20 \text{ k}\Omega$		-	25	V
V _{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	124	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	185	A
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	139	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3		-	786	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C

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Symbol	Parameter	Conditions		Min	Max	Unit
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain	n diode					
I _S	source current	T _{mb} = 25 °C		-	124	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	786	Α
Avalanche r	uggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$ \begin{array}{l} {\sf I}_{\sf D} = 25 \; {\sf A}; \; {\sf V}_{sup} \leq \; 25 \; {\sf V}; \; {\sf R}_{\sf GS} = 50 \; \Omega; \\ {\sf V}_{\sf GS} = 10 \; {\sf V}; \; {\sf T}_{j(init)} = 25 \; {}^{\circ}{\sf C}; \; unclamped; \\ {\sf t}_p = 957 \; \mu s \end{array} $	[2]	-	389	mJ
I _{AS}	non-repetitive avalanche current	$V_{sup} \le 25 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C}; R_{GS} = 50 \Omega$	[2]	-	80	A

[1] 185 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Protected by 100% test.

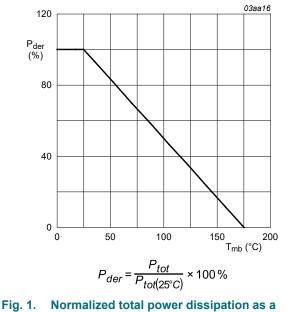
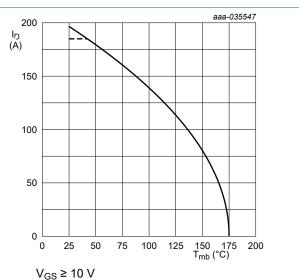


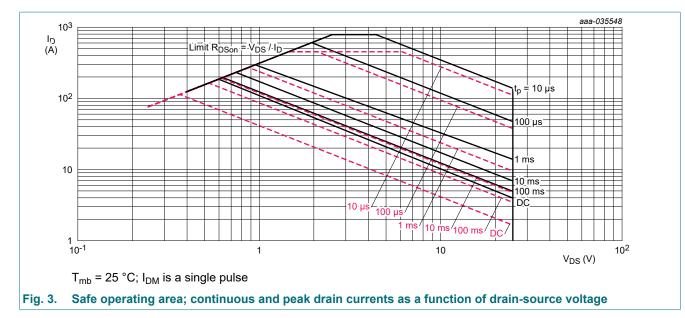
fig. 1. Normalized total power dissipation as a function of mounting base temperature



(1) 185 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

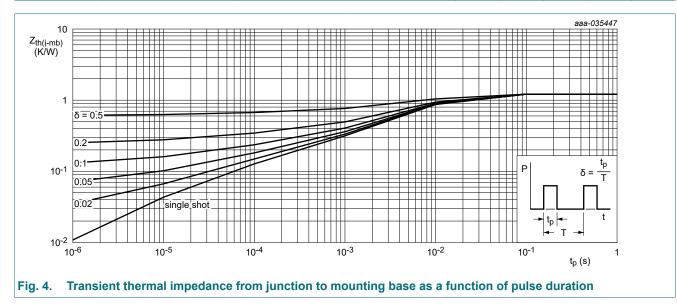
Fig. 2. Continuous drain current as a function of mounting base temperature

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9. Thermal characteristics

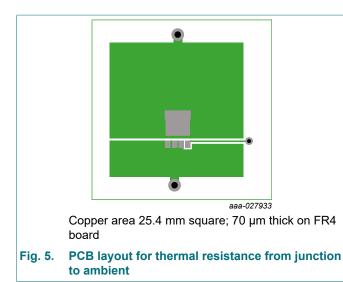
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 4</u>	-	0.63	1.21	K/W
R _{th(j-a)}	thermal resistance from	<u>Fig. 5</u>	-	42	-	K/W
	junction to ambient	Fig. 6	-	85	-	K/W

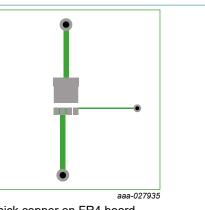


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70 μm thick copper on FR4 board

Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient

10. Characteristics

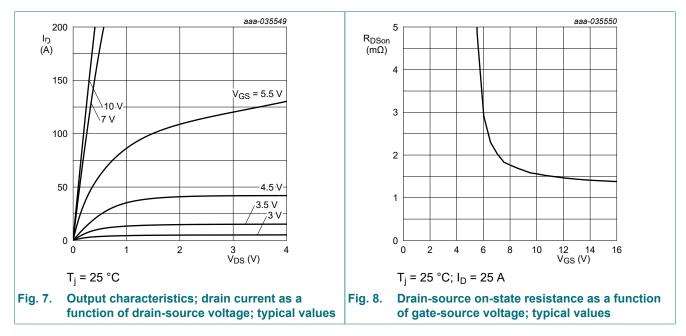
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Static charac	teristics	· · · ·				
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	25	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	22.5	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.2	1.91	2.2	V
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-3.3	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{DS} = 20 V; V _{GS} = 0 V; T _j = 125 °C	-	1.7	-	μA
I _{GSS}	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10	-	1.68	1.88	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 150 °C; Fig. 11	-	-	3.4	mΩ
		V _{GS} = 7 V; I _D = 25 A; T _j = 25 °C; <u>Fig. 10</u>	-	2.18	2.4	mΩ
		V _{GS} = 7 V; I _D = 25 A; T _j = 150 °C; Fig. 11	-	-	4.3	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	1.1	2.8	6.9	Ω
Dynamic cha	racteristics					
Q _{G(tot)}	total gate charge	$I_{D} = 25 \text{ A}; V_{DS} = 12 \text{ V}; V_{GS} = 4.5 \text{ V}; T_{j} = 25 \text{ °C}; Fig. 12; Fig. 13$	7	16	27	nC
		$I_{D} = 25 \text{ A}; V_{DS} = 12 \text{ V}; V_{GS} = 10 \text{ V}; T_{j} = 25 \text{ °C}; Fig. 12; Fig. 13$	16	37	61	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V};$ $T_i = 25 \text{ °C}$	-	19	-	nC

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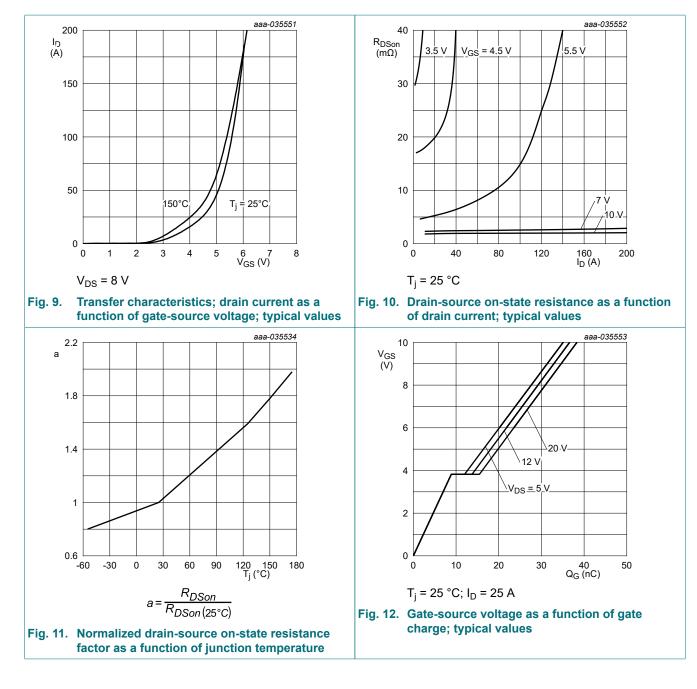
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 12 V; V _{GS} = 4.5 V;		2	9	17	nC
Q _{GS(th)}	pre-threshold gate- source charge	T _j = 25 °C; <u>Fig. 12</u> ; <u>Fig. 13</u>		1	4	8	nC
Q _{GS(th-pl)}	post-threshold gate- source charge	-		1	5	10	nC
Q _{GD}	gate-drain charge	-		0.9	5	10	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 12 V; T _j = 25 °C; Fig. 12; Fig. 13		-	3.8	-	V
C _{iss}	input capacitance	V _{DS} = 12 V; V _{GS} = 0 V; f = 1 MHz;		1479	2465	3698	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u>		873	1455	2183	pF
C _{rss}	reverse transfer capacitance			54	199	478	pF
t _{d(on)}	turn-on delay time	V_{DS} = 12 V; R _L = 0.5 Ω; V _{GS} = 4.5 V;		-	22	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$		-	72	-	ns
t _{d(off)}	turn-off delay time	_		-	12	-	ns
t _f	fall time	_		-	18	-	ns
Q _{oss}	output charge	V _{GS} = 0 V; V _{DS} = 12 V; f = 1 MHz; T _j = 25 °C		-	24	-	nC
Source-drai	n diode			-			
V _{SD}	source-drain voltage	$I_{S} = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_{j} = 25 \text{ °C}; Fig. 15$		-	0.8	1	V
t _{rr}	reverse recovery time	$I_{S} = 25 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$		-	25	-	ns
Q _r	recovered charge	V _{DS} = 12 V; T _j = 25 °C; <u>Fig. 16</u>	[1]	-	13	-	nC
t _a	reverse recovery rise time			-	11.9	-	ns
t _b	reverse recovery fall time			-	12.6	-	ns
S	softness factor			-	1.06	-	
		1					

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[1] includes capacitive recovery

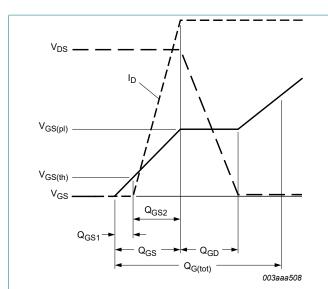


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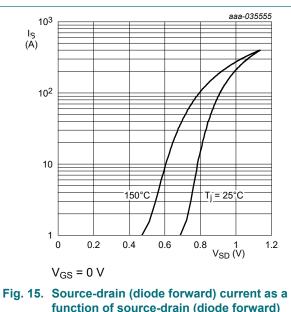


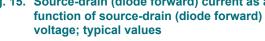
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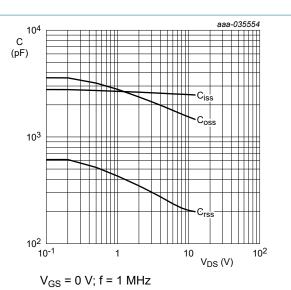
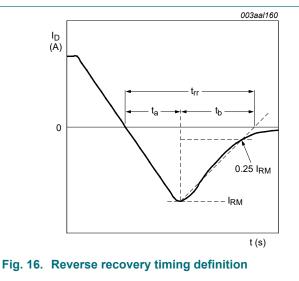
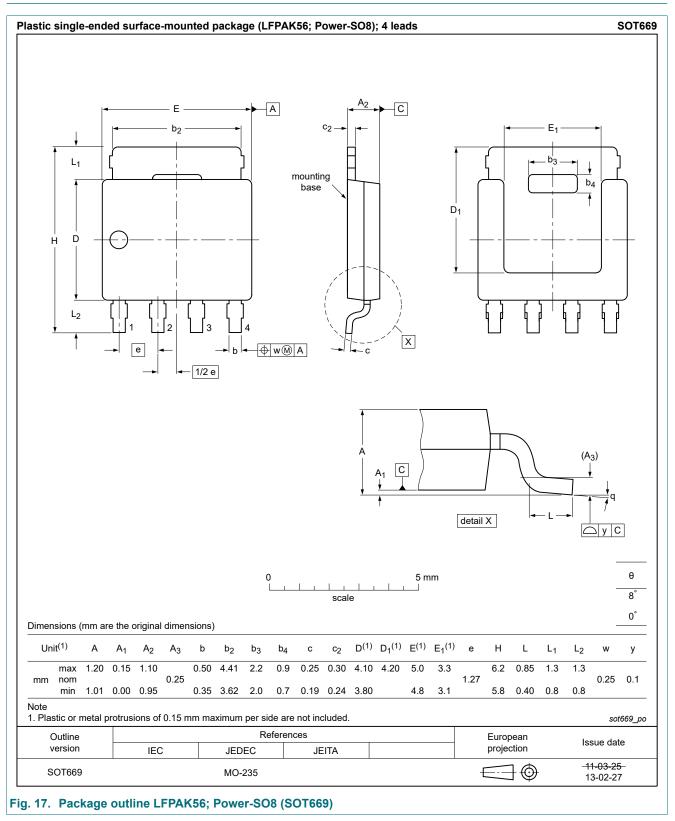


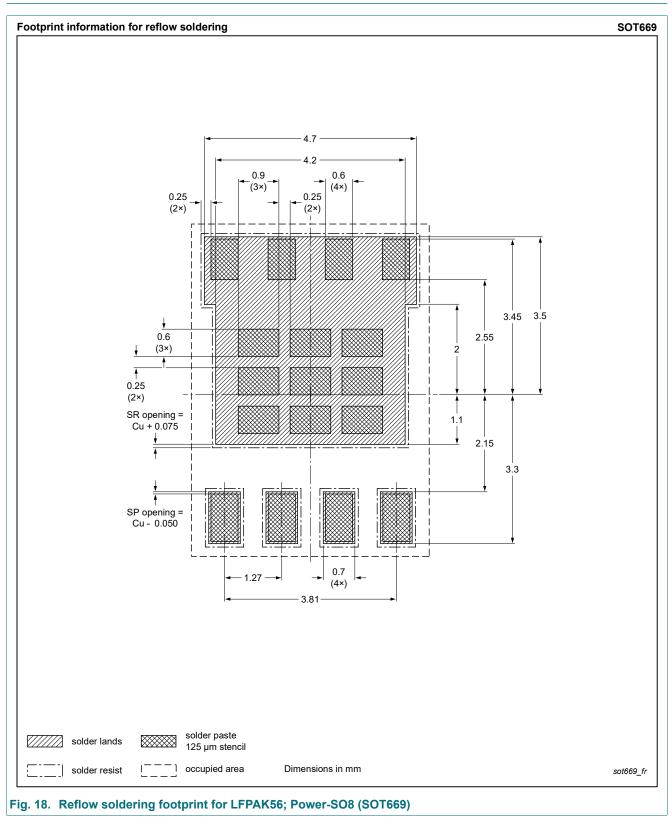
Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



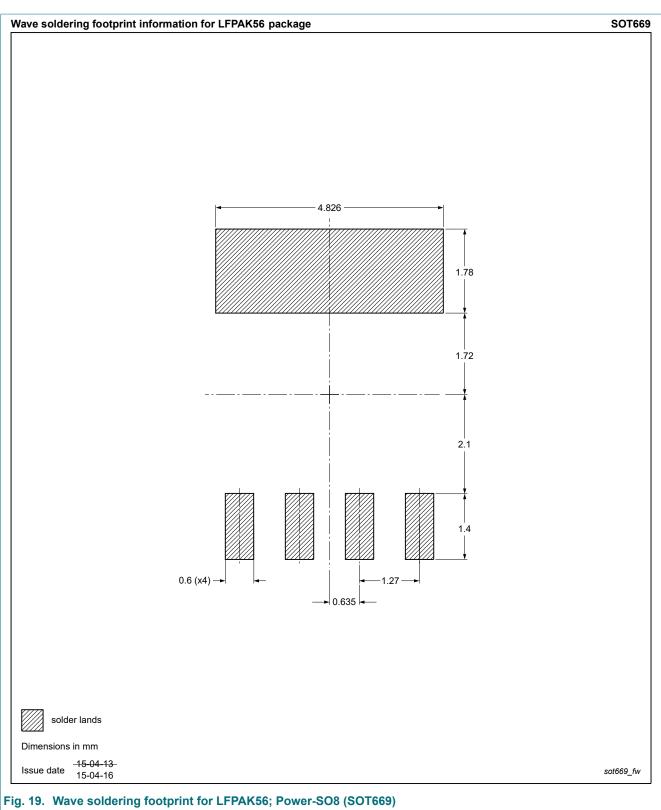
11. Package outline



12. Soldering







13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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 Please consult the most recently issued document before initiating or completing a design.

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